

WS72632

## 9MHz Rail-to-Rail Input Output CMOS **Operational Amplifiers**

### **Descriptions**

The WS72632 is a low power rail-to-rail input output operational amplifier featuring low current noise, high slew rate and wide signal bandwidth. The combination of low noise, low input bias currents, high speed and inside EMI filter make this amplifier useful in a wide variety of applications. Filters, integrators, photo-diode amplifiers, and high impedance sensors all benefit from this combination of performance features. Audio and other ac applications benefit from the wide bandwidth and low distortion of this device. Applications for this amplifier include power amplifier (PA) controls, laser diode control loops, portable and loop-powered instrumentation, audio amplification for portable devices, and ASIC input and output amplifiers. The WS72632 is dual channel version available in SOP-8L package, MSOP-8L package and TSSOP-8L package.

### Applications

- Sensor Signal Conditioning
- **Consumer Audio**
- Multi-Pole Active Filters
- Communications •
- Security
- Scanners

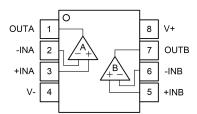
### Features

- Gain-bandwidth Product : 9 MHz
  - : 12.5 nV/ √ Hz(f= 1kHz) Low Noise
- Slew Rate : 5 V/µs
- Offset Voltage : 3 mV (max)
- Supply Range : 2.2 V to 5.5 V •
- : 720 uA/ch Supply Current
- High Output Current : 130 mA
- Low THD+N : -100dB
- Rail-to-Rail Input/Output Swing
- 40°C to 125°C Operation Range
- Robust 8kV HBM and 400V MM and 2kV CDM

# SOP-8L **TSSOP-8L** MSOP-8L SOT23-8L

Http://www.omnivision-group.com





# SOP-8L/MSOP-8L /TSSOP-8L/SOT23-8L

Pin configuration (Top view)

SOP-8L	MSOP-8L	TSSOP-8L	SOT23-8L
WLSI 2632 OGSYW	2632 GMYW	2632 GHYW	2412 GEYW

SOP-8L

Marking					
2632、2412	= Device code				
GS、GM、GH、GE	= Special code				
Y	= Year code				
W	= Week code				

## **Order Information**

Device	Package	Shipping
WS72632S-8/TR	SOP-8L	4000/Reel &Tape
WS72632M-8/TR	MSOP-8L	4000/Reel &Tape
WS72632H-8/TR	TSSOP-8L	4000/Reel &Tape
WS72632E-8/TR	SOT23-8L	3000/Reel &Tape



### **Pin Descriptions**

Pin Number	Symbol	Descriptions
1	OUTA	Output of Amplifier A
2	-INA	Inverting input of Amplifier A
3	+INA	Non-inverting input of Amplifier A
4	V-	Negative supply
5	+INB	Non-inverting input of Amplifier B
6	-INB	Inverting input of Amplifier B
7	OUTB	Output of Amplifier B
8	V+	Positive supply

### **Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit
Supply Voltage, ([V+] – [V-])	Vs <sup>(2)</sup>	6	V
Input Differential Voltage	$V_{IDR}^{(3)}$	±6	V
Input Common Mode Voltage Range	VICR	(V-)-0.2 to (V+)+0.2	V
Output Short-Circuit Duration	t <sub>so</sub>	Unlimited	/
Operating Fee-Air Temperature Range	T <sub>A</sub>	-40 to 125	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to 150	°C
Junction Temperature Range	TJ	150	°C
Lead Temperature Range	TL	260	°C

Note:

- Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are only stress ratings, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions are not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- 2. All voltage values, except differential voltage are with respect to network terminal.
- 3. Differential voltages are at +IN with respect to -IN.

### **ESD**, Electrostatic Discharge Protection

Symbol	Parameter	Condition	Minimum level	Unit
НВМ	Human Body Model ESD	MIL-STD-883H Method 3015.8	±8000	v
	JEDEC-EIA/JESD22-A114A		-	
MM	Machine Model ESD	JEDEC-EIA/JESD22-A115	±400	V
CDM	Charged Device Model ESD	JEDEC-EIA/JESD22-C101E	±2000	V



### **Electronics Characteristics**

The \*denotes the specifications which apply over the full operating temperature range, otherwise specifications are at  $T_A = 25^{\circ}C$ ,  $V_S = 5V$ ,  $V_{CM} = V_{OUT} = V_S/2$ ,  $R_{load} = 100k\Omega$ ,  $C_{load} = 100pF$ .

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Vos	Input Offset Voltage	V <sub>CM</sub> = V <sub>S</sub> /2	-3	±0.1	+3	mV
avos	Input Offset Voltage Drift	-40°C to 125°C		2		µV/°C
I <sub>IB</sub>	Input Bias Current			10		pА
los	Input Offset Current			10		pА
Vn	Input Voltage Noise	f=0.1Hz to 10Hz		0.9		μV <sub>P-P</sub>
en	Input Voltage Noise Density	f=1kHz		12.5		nV/√Hz
CMRR	Common Mode Rejection Ratio	V <sub>CM</sub> = -0.1V to 5.1V	60	90		dB
V <sub>CM</sub>	Common Mode Input Voltage Range		(V-)-0.1		(V+)+0.1	V
PSRR	Power Supply Rejection Ratio	$V_{S}$ = 2.2V to 5.5V, $V_{CM}$ = 0V	80	120		dB
A <sub>VOL</sub>	Open Loop Large Signal Gain	$V_{OUT} = 0.1V$ to 4.9V	80	100		dB
		$R_{load}=2k\Omega$		13		mV
V <sub>OH</sub>	High Level Output Voltage	$R_{load}$ =10k $\Omega$		2		mV
	Low Level Output Voltage	$R_{load}=2k\Omega$		8		mV
Vol		$R_{load}$ =10k $\Omega$		2		mV
Rout	Closed-Loop Output Impedance	G = 1, f =1MHz, I <sub>OUT</sub> = 0		0.5		Ω
		Source Current		130		mA
Isc	Output Short-Circuit Current	Sink Current		130		mA
Vs	Supply Voltage		2.2		5.5	V
lα	Quiescent Current per Amplifier	Vs=5V		720	900	uA
PM	Phase Margin	$R_{load}$ =1k $\Omega$ , $C_{load}$ =60pF		60		degrees
GM	Gain Margin	$R_{load}$ =1k $\Omega$ , $C_{load}$ =60pF		10		dB
GBWP	Gain-Bandwidth Product	f=1kHz		9		MHz
ts	0.1% Settling Time	1.5 to 3.5V, Unity Gain		0.5		μs
SR	Slew Rate	A <sub>V</sub> =1, R <sub>load</sub> =2kΩ, C <sub>load</sub> =100pF		5		V/µs
FPBW	Full Power Bandwidth	2V <sub>P-P</sub>		800		kHz
THD+N	Total Harmonic Distortion and Noise	f=1kHz, AV=1, R <sub>load</sub> =2kΩ, V <sub>OUT</sub> =1V <sub>PP</sub>		-100		dB
X <sub>talk</sub>	Channel Separation	$f = 1 \text{ kHz}, \text{ RL} = 2 \text{ k}\Omega$		110		dB



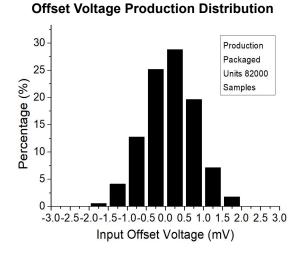
### Note:

- 1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.
- 2. A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.
- 3. Thermal resistance varies with the amount of PC board metal connected to the package. The specified values are for short traces connected to the leads.
- 4. Full power bandwidth is calculated from the slew rate FPBW = SR/( $\pi \cdot V_{P-P}$ ).

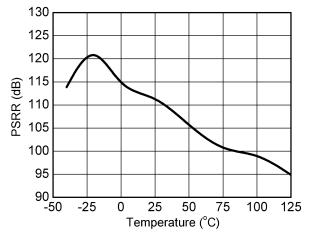


### **Typical Characteristics**

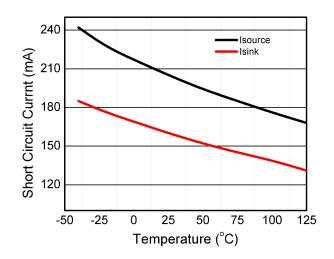
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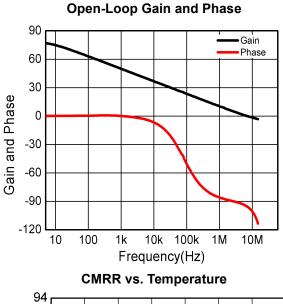


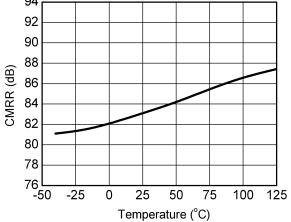


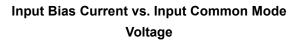


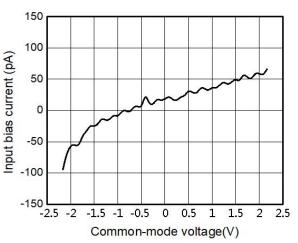










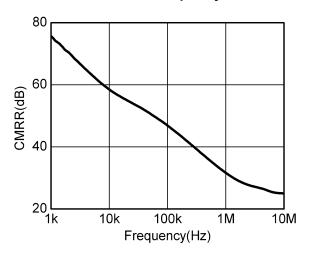




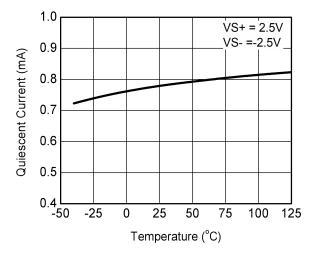
### **Typical Characteristics (continued)**

 $T_{A}\text{=}25^{\circ}\text{C},~V_{S}\text{=}\pm2.5\text{V},~V_{CM}\text{=}0\text{V},$  unless otherwise noted

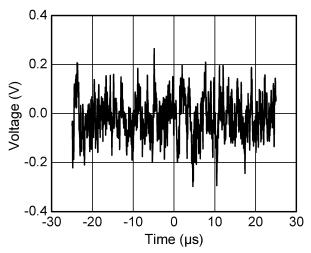
CMRR vs. Frequency



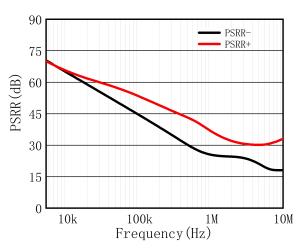
### **Quiescent Current vs. Temperature**



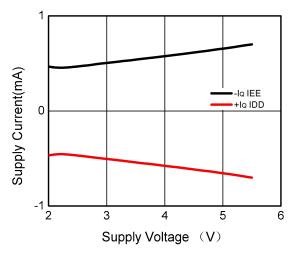




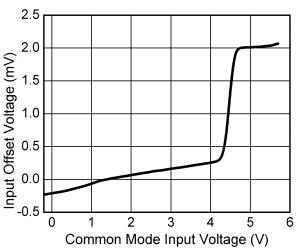
Power-Supply Rejection Ratio vs. Frequency



**Quiescent Current vs. Supply Voltage** 





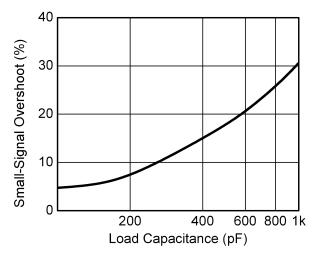




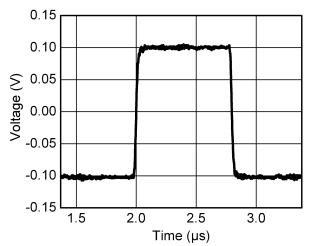
### **Typical Characteristics (continued)**

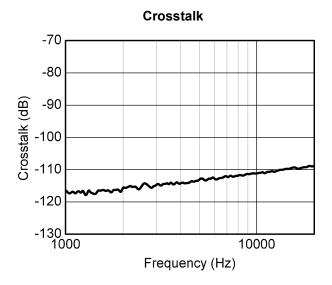
 $T_A=25^{\circ}C$ ,  $V_S=\pm 2.5V$ ,  $V_{CM}=0V$ , unless otherwise noted

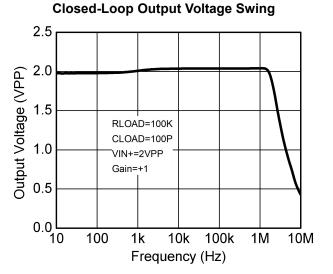
Small-Signal Overshoot vs. Load Capacitance



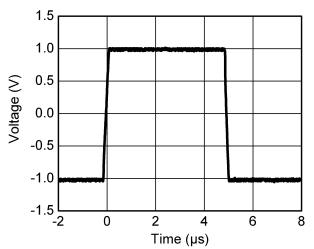


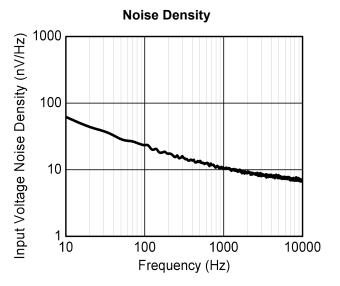






Large-Scale Step Response, 2V Step

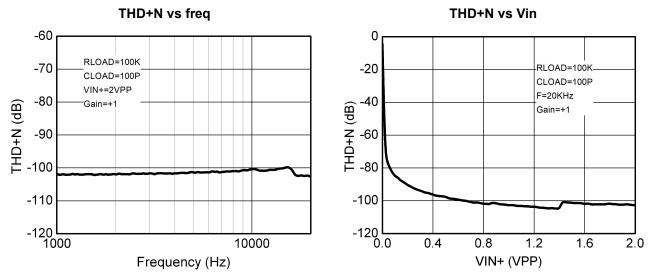






### **Typical Characteristics (continued)**

 $T_{A}\text{=}25^{\circ}\text{C},~V_{S}\text{=}\pm2.5\text{V},~V_{\text{CM}}\text{=}0\text{V},$  unless otherwise noted



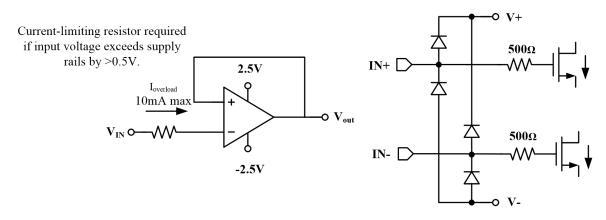


### Operation

The WS72632 series op amps can operate on a single-supply voltage (2.2 V to 5.5 V), or a split-supply voltage ( $\pm$ 1.1 V to  $\pm$ 2.75 V), making them highly versatile and easy to use. The power-supply pins should have local bypass ceramic capacitors (typically 0.001 µF to 0.1 µF). These amplifiers are fully specified from +2.2 V to +5.5 V and over the extended temperature range of -40°C to +125°C. Parameters that can exhibit variance with regard to operating voltage or temperature are presented in the Typical Characteristics.

### Input ESD Diode Protection

The WS72632 incorporates internal electrostatic discharge (ESD) protection circuits on all pins. In the case of input and output pins, this protection primarily consists of current-steering diodes connected between the input and power-supply pins. These ESD protection diodes also provide in-circuit input overdrive protection, as long as the current is limited to 10 mA as stated in the Absolute Maximum Ratings table. Many input signals are inherently current-limited to less than 10 mA; therefore, a limiting resistor is not required. Figure 1 shows how a series input resistor (RS) may be added to the driven input to limit the input current. The added resistor contributes thermal noise at the amplifier input and the value should be kept to the minimum in noise-sensitive applications.



INPUT ESD DIODE CURRENT LIMITING- UNITY GAIN

### Figure1. Input ESD Diode

### PCB Surface Leakage

In applications where low input bias current is critical, Printed Circuit Board (PCB) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is  $1012 \Omega$ . A 5V difference would cause 5pA of current to flow, which is greater than the WS72631 OPA' s input bias current at +27° C (±3pA, typical). It is recommended to use multi-layer PCB layout and route the OPA' s -IN and +IN signal under the PCB surface.

The effective way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. An example of this type of layout is shown in Figure 1 for Inverting Gain application.

1. For Non-Inverting Gain and Unity-Gain Buffer:



a) Connect the non-inverting pin (VIN+) to the input with a wire that does not touch the PCB surface.

b) Connect the guard ring to the inverting input pin (VIN–). This biases the guard ring to the Common Mode input voltage.

2. For Inverting Gain and Trans-impedance Gain Amplifiers (convert current to voltage, such as photo detectors):

a) Connect the guard ring to the non-inverting input pin (VIN+). This biases the guard ring to the same reference voltage as the op-amp (e.g., VDD/2 or ground).

b) Connect the inverting pin (VIN–) to the input with a wire that does not touch the PCB surface.

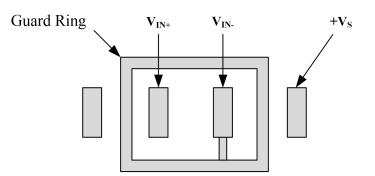


Figure 2 The Layout of Guard Ring

## Power Supply Layout and Bypass

The WS72632 OPA's power supply pin (VDD for single-supply) should have a local bypass capacitor (i.e.,  $0.01\mu$ F to  $0.1\mu$ F) within 2mm for good high frequency performance. It can also use a bulk capacitor (i.e.,  $1\mu$ F or larger) within 100mm to provide large, slow currents. This bulk capacitor can be shared with other analog parts.

Ground layout improves performance by decreasing the amount of stray capacitance and noise at the OPA's inputs and outputs. To decrease stray capacitance, minimize PC board lengths and resistor leads, and place external components as close to the op amps' pins as possible.

### **Proper Board Layout**

To ensure optimum performance at the PCB level, care must be taken in the design of the board layout. To avoid leakage currents, the surface of the board should be kept clean and free of moisture. Coating the surface creates a barrier to moisture accumulation and helps reduce parasitic resistance on the board.

Keeping supply traces short and properly bypassing the power supplies minimizes power supply disturbances due to output current variation, such as when driving an ac signal into a heavy load. Bypass capacitors should be connected as closely as possible to the device supply pins. Stray capacitances are a concern at the outputs and the inputs of the amplifier. It is recommended that signal traces be kept at least 5mm from supply lines to minimize coupling.

A variation in temperature across the PCB can cause a mismatch in the Seebeck voltages at solder joints and other points where dissimilar metals are in contact, resulting in thermal voltage errors. To minimize these thermocouple effects, orient resistors so heat sources warm both ends equally. Input signal paths should

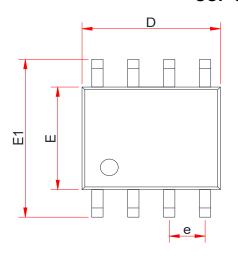


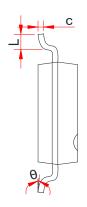
contain matching numbers and types of components, where possible to match the number and type of thermocouple junctions. For example, dummy components such as zero value resistors can be used to match real resistors in the opposite input path. Matching components should be located in close proximity and should be oriented in the same manner. Ensure leads are of equal length so that thermal conduction is in equilibrium. Keep heat sources on the PCB as far away from amplifier input circuitry as is practical.

The use of a ground plane is highly recommended. A ground plane reduces EMI noise and also helps to maintain a constant temperature across the circuit board.

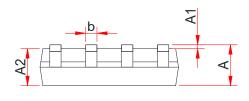


SOP-8L









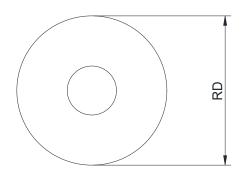
SIDE VIEW

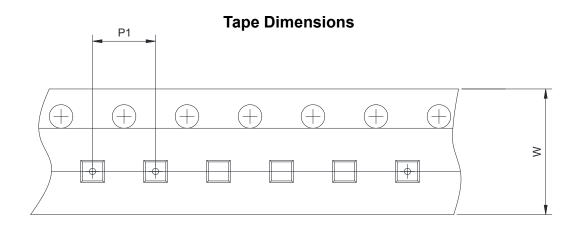
Symbol	Dimensions In Millimeters (mm)				
Symbol	Min.	Тур.	Max.		
A	1.35	1.55	1.75		
A1	0.05	0.15	0.25		
A2	1.25	1.40	1.65		
b	0.33	-	0.51		
с	0.15	-	0.26		
D	4.70	4.90	5.10		
E	3.70	3.90	4.10		
E1	5.80	6.00	6.20		
е	1.27BSC				
L	0.40	-	1.27		
θ	0°	-	8°		



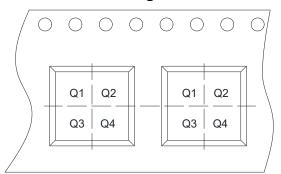
### SOP-8L

### **Reel Dimensions**





# **Quadrant Assignments For PIN1 Orientation In Tape**

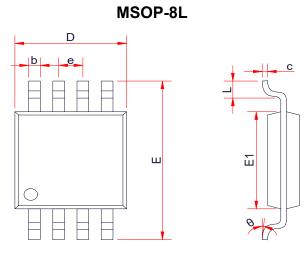




User Direction of Feed

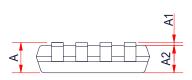
RD	Reel Dimension	Tinch	🔽 13inch		
W	Overall width of the carrier tape	🔲 8mm	🔽 12mm		
P1	Pitch between successive cavity centers	🔲 2mm	🔲 4mm	🗹 8mm	
Pin1	Pin1 Quadrant	🗹 Q1	🗖 Q2	🗖 Q3	🗖 Q4





TOP VIEW

SIDE VIEW



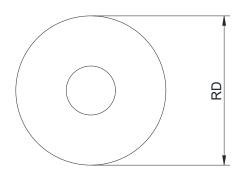
SIDE VIEW

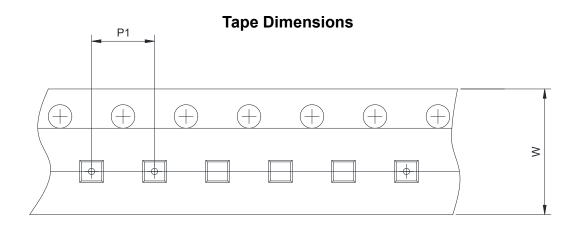
Symbol	Dimensions In Millimeters (mm)					
	Min.	Min. Typ.				
A	-	-	1.10			
A1	0.02	-	0.15			
A2	0.75	0.80 0.95				
b	0.25	-	0.38			
с	0.09	-	0.23			
D	2.90	3.00	3.10			
E	4.75	4.90	5.05			
E1	2.90	3.00 3.10				
е	0.65 BSC					
L	0.40	-	0.80			
θ	0°	- 6°				



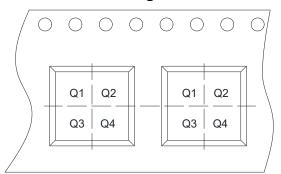
### MSOP-8L

### **Reel Dimensions**





# **Quadrant Assignments For PIN1 Orientation In Tape**

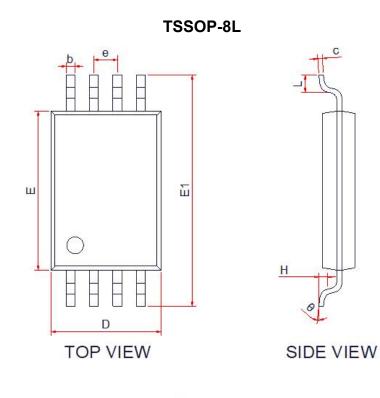


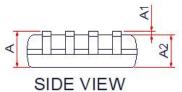


User Direction of Feed

RD	Reel Dimension	Tinch	🔽 13inch		
W	Overall width of the carrier tape	🔲 8mm	🔽 12mm		
P1	Pitch between successive cavity centers	🔲 2mm	🔲 4mm	🗹 8mm	
Pin1	Pin1 Quadrant	🗹 Q1	🗖 Q2	C Q3	🗖 Q4





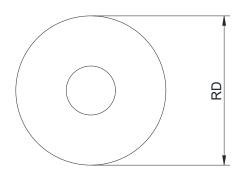


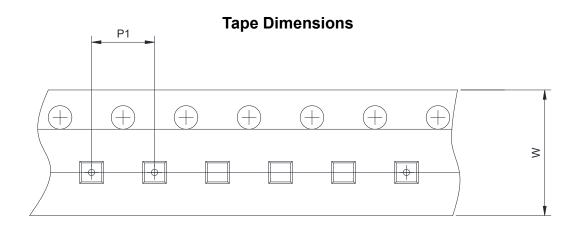
Symbol	Dimensions In Millimeters (mm)				
	Min.	Тур.	Max.		
А	-	-	1.20		
A1	0.05	-	0.15		
A2	0.80	-	1.05		
b	0.19	-	0.30		
с	0.09	-	0.20		
D	2.90	3.00	3.10		
E	4.30	4.40	4.50		
E1	6.25	6.40	6.55		
е	0.65 BSC				
L	0.45	-	0.75		
θ	0°	- 8°			



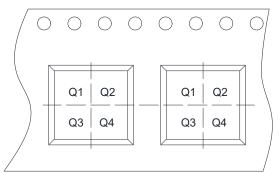
# **TSSOP-8L**

### **Reel Dimensions**





# **Quadrant Assignments For PIN1 Orientation In Tape**

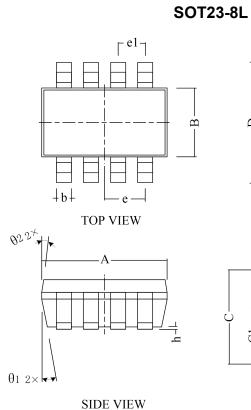




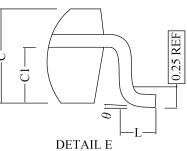
User Direction of Feed

RD	Reel Dimension	Tinch	🔽 13inch		
W	Overall width of the carrier tape	🔲 8mm	🔽 12mm		
P1	Pitch between successive cavity centers	🗖 2mm	🔲 4mm	🗹 8mm	
Pin1	Pin1 Quadrant	🔽 Q1	🗖 Q2	🗖 Q3	🗖 Q4





SIDE VIEW

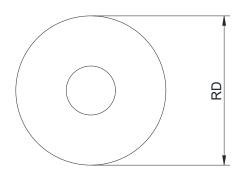


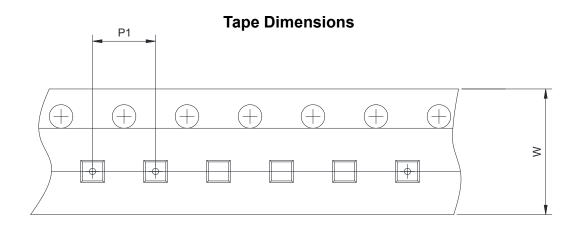
Symbol	Dimensions In Millimeters (mm)				
	Min.	Тур.	Max.		
А	2.820	2.920	3.020		
В	1.500	1.600	1.700		
С	1.050	1.100	1.150		
C1	0.600	0.650	0.700		
D	2.650	2.800	2.950		
L	0.300	0.450	0.600		
b	0.320	0.400	0.480		
h	0.020	0.050	0.100		
К	0.100		0.200		
е	0.950 TYPE				
e1	0.633 TYPE				
θ1	8° TYPE				
θ2	8° TYPE				
θ3	8° TYPE				
θ4	8° TYPE				
θ	0°~8°				



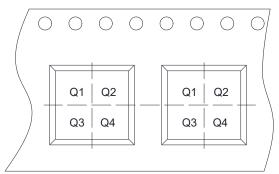
### SOT23-8L

### **Reel Dimensions**





# **Quadrant Assignments For PIN1 Orientation In Tape**





User Direction of Feed

RD	Reel Dimension	🗹 7inch	🔲 13inch		
W	Overall width of the carrier tape	🗹 8mm	🔲 12mm		
P1	Pitch between successive cavity centers	🔲 2mm	🗹 4mm	🔲 8mm	
Pin1	Pin1 Quadrant	🗖 Q1	🗖 Q2	✓ Q3	🗖 Q4